

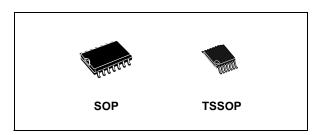


# LOW VOLTAGE CMOS QUAD 2-INPUT OR GATE HIGH PERFORMANCE

- 5V TOLERANT INPUTS
- HIGH SPEED:  $t_{PD} = 4.2$ ns (MAX.) at  $V_{CC} = 3V$
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:  $|I_{OH}| = I_{OI} = 24\text{mA}$  (MIN) at  $V_{CC} = 3V$
- PCI BUS LEVELS GUARANTEED AT 24 mA
- BALANCED PROPAGATION DELAYS: tpi h ≅ tphi
- OPERATING VOLTAGE RANGE:
   V<sub>CC</sub>(OPR) = 1.65V to 3.6V (1.2V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 32
- LATCH-UP PERFORMANCE EXCEEDS 500mA (JESD 17)
- ESD PERFORMANCE: HBM > 2000V (MIL STD 883 method 3015); MM > 200V

#### **DESCRIPTION**

The 74LVC32A is a low voltage CMOS QUAD 2-INPUT OR GATE fabricated with sub-micron silicon gate and double-layer metal wiring  $\rm C^2MOS$  technology. It is ideal for 1.65 to 3.6  $\rm V_{CC}$ 



**Table 1: Order Codes** 

PACKAGE	T & R
SOP	74LVC32AMTR
TSSOP	74LVC32ATTR

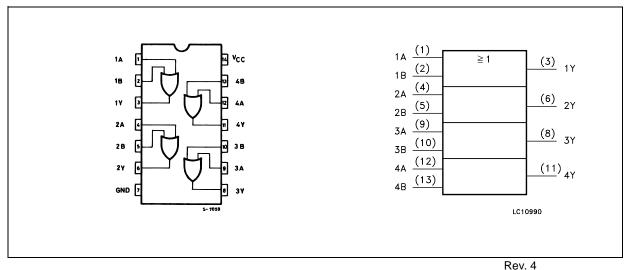
operations and low power and low noise applications.

It can be interfaced to 5V signal environment for inputs in mixed 3.3/5V system.

It has more speed performance at 3.3V than 5V AC/ACT family, combined with a lower power consumption.

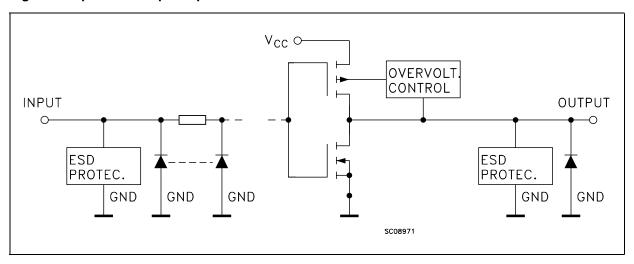
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

Figure 1: Pin Connection And IEC Logic Symbols



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Figure 2: Input And Output Equivalent Circuit



**Table 2: Pin Description** 

PIN N°	SYMBOL	NAME AND FUNCTION
1, 4, 9, 12	1A to 4A	Data Inputs
2, 5, 10, 13	1B to 4B	Data Inputs
3, 6, 8, 11	1Y to 4Y	Data Outputs
7	GND	Ground (0V)
14	V <sub>CC</sub>	Positive Supply Voltage

**Table 3: Truth Table** 

Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

**Table 4: Absolute Maximum Ratings** 

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0	V
VI	DC Input Voltage	-0.5 to +7.0	V
Vo	DC Output Voltage (V <sub>CC</sub> = 0V)	-0.5 to +7.0	V
Vo	DC Output Voltage (High or Low State) (note 1)	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	DC Input Diode Current	- 50	mA
l <sub>ok</sub>	DC Output Diode Current (note 2)	- 50	mA
I <sub>O</sub>	DC Output Current	± 50	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current per Supply Pin	± 100	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

1) I<sub>O</sub> absolute maximum rating must be observed
2) V<sub>O</sub> < GND

**Table 5: Recommended Operating Conditions** 

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage (note 1)	1.65 to 3.6	V
V <sub>I</sub>	Input Voltage	0 to 5.5	V
Vo	Output Voltage (V <sub>CC</sub> = 0V)	0 to 5.5	V
Vo	Output Voltage (High or Low State)	0 to V <sub>CC</sub>	V
I <sub>OH</sub> , I <sub>OL</sub>	High or Low Level Output Current (V <sub>CC</sub> = 3.0 to 3.6V)	± 24	mA
I <sub>OH</sub> , I <sub>OL</sub>	High or Low Level Output Current (V <sub>CC</sub> = 2.7 to 3.0V)	± 12	mA
I <sub>OH</sub> , I <sub>OL</sub>	High or Low Level Output Current (V <sub>CC</sub> = 2.3 to 2.7V)	± 8	mA
I <sub>OH</sub> , I <sub>OL</sub>	High or Low Level Output Current (V <sub>CC</sub> = 1.65 to 2.3V)	± 4	mA
T <sub>op</sub>	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time (note 2)	0 to 10	ns/V

<sup>1)</sup> Truth Table guaranteed: 1.2V to 3.6V

**Table 6: DC Specifications** 

		Test	Condition		Va	lue			
Symbol	Parameter	V <sub>CC</sub>	V <sub>CC</sub>		85 °C	-55 to	125 °C	Unit	
		(V)		Min.	Max.	Min.	Max.		
$V_{IH}$	High Level Input	1.65 to 1.95		0.65V <sub>CC</sub>		0.65V <sub>CC</sub>			
	Voltage	2.3 to 2.7		1.7		1.7		V	
		2.7 to 3.6		2		2			
$V_{IL}$	Low Level Input	1.65 to 1.95			0.35V <sub>CC</sub>		0.35V <sub>CC</sub>		
	Voltage	2.3 to 2.7			0.7		0.7	V	
		2.7 to 3.6			0.8		0.8		
$V_{OH}$	High Level Output	1.65 to 3.6	I <sub>O</sub> =-100 μA	V <sub>CC</sub> -0.2		V <sub>CC</sub> -0.2			
	Voltage	1.65	I <sub>O</sub> =-4 mA	1.2		1.2			
		2.3	I <sub>O</sub> =-8 mA	1.7		1.7		V	
		2.7	I <sub>O</sub> =-12 mA	2.2		2.2			
		3.0	I <sub>O</sub> =-18 mA	2.4		2.4			
		3.0	I <sub>O</sub> =-24 mA	2.2		2.2			
V <sub>OL</sub>	Low Level Output	1.65 to 3.6	I <sub>O</sub> =100 μA		0.2		0.2		
	Voltage	1.65	I <sub>O</sub> =4 mA		0.45		0.45		
		2.3	I <sub>O</sub> =8 mA		0.7		0.7	V	
		2.7	I <sub>O</sub> =12 mA		0.4		0.4		
		3.0	I <sub>O</sub> =24 mA		0.55		0.55		
I <sub>I</sub>	Input Leakage Current	3.6	$V_{I} = 0 \text{ to } 5.5V$		± 5		± 5	μΑ	
I <sub>off</sub>	Power Off Leakage Current	0	$V_I$ or $V_O = 5.5V$		10		10	μА	
I <sub>CC</sub>	Quiescent Supply		$V_I = V_{CC}$ or GND		10		10		
	Current	3.6	$V_{I}$ or $V_{O} = 3.6$ to 5.5V		± 10		± 10	μΑ	
$\Delta I_{CC}$	I <sub>CC</sub> incr. per Input	2.7 to 3.6	$V_{IH} = V_{CC}$ -0.6V		500		500	μΑ	

<sup>2)</sup>  $V_{IN}$  from 0.8V to 2V at  $V_{CC}$  = 3.0V

**Table 7: Dynamic Switching Characteristics** 

Ī			Tes	Test Condition				
	Symbol	Parameter	v <sub>cc</sub>		T <sub>A</sub> = 25 °C		Unit	
			(V)		Min.	Тур.	Max.	
Î	V <sub>OLP</sub>	Dynamic Low Level Quiet	3.3	C <sub>L</sub> = 50pF		0.8		\/
I	$V_{OLV}$	Output (note 1)	3.3	$V_{IL} = 0V, V_{IH} = 3.3V$		-0.8		V

<sup>1)</sup> Number of output defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.

**Table 8: AC Electrical Characteristics** 

		Test Condition			Value					
Symbol	Parameter		CL	Rı	$R_L$ $t_s = t_r$ $(\Omega)$ $(ns)$	-40 to 85 °C		-55 to 125 °C		Unit
			(p <del>F</del> )			Min.	Max.	Min.	Max.	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay	1.65 to 1.95	30	1000	2.0		8.9		12	
	Time	2.3 to 2.7	30	500	2.0		5.9		8.0	
		2.7	50	500	2.5		4.8		5.8	ns
		3.0 to 3.6	50	500	2.5	1	4.2	1	5.0	
t <sub>OSLH</sub> t <sub>OSHL</sub>	Output To Output Skew Time (note1, 2)	2.7 to 3.6					1		1	ns

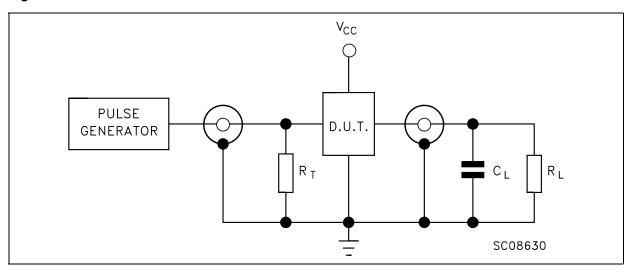
<sup>1)</sup> Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW (t<sub>OSLH</sub> = | t<sub>PLHm</sub> - t<sub>PLHn</sub>|, t<sub>OSHL</sub> = | t<sub>PHLm</sub> - t<sub>PHLn</sub>| 2) Parameter guaranteed by design

**Table 9: Capacitive Characteristics** 

		Tes	Value				
Symbol	Parameter	V <sub>CC</sub>		T <sub>A</sub> = 25 °C			Unit
		(V)		Min.	Тур.	Max.	
C <sub>IN</sub>	Input Capacitance				4		pF
C <sub>PD</sub>	Power Dissipation Capacitance	1.8	f <sub>IN</sub> = 10MHz		32		
	(note 1)	2.5			33		pF
		3.3			37		

<sup>1)</sup>  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/n$  (per circuit)

Figure 3: Test Circuit

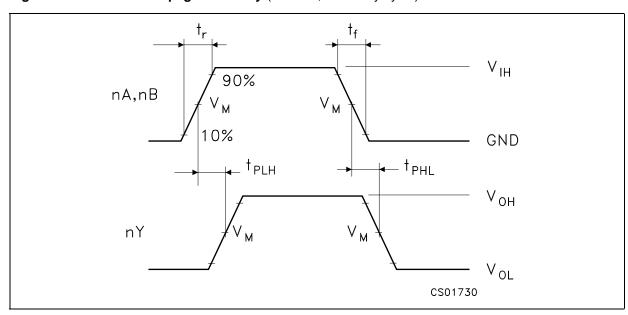


 $R_T = Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

**Table 10: Test Circuit And Waveform Symbol Value** 

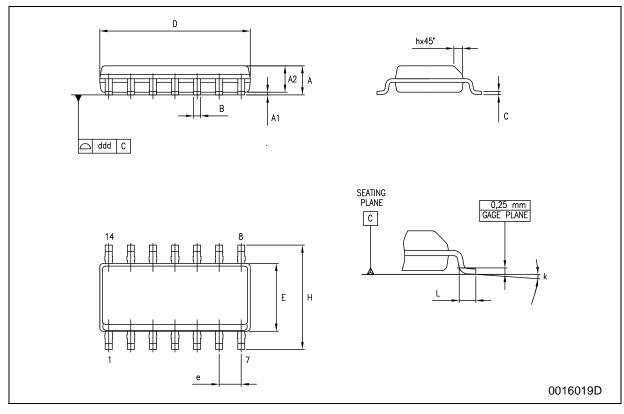
Symbol	V <sub>CC</sub>							
Зушьог	1.65 to 1.95V	2.3 to 2.7V	2.7V	3.0 to 3.6V				
C <sub>L</sub>	30pF	30pF	50pF	50pF				
$R_{L}$	1000Ω	500Ω	500Ω	500Ω				
V <sub>IH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	2.7V	2.7V				
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	1.5V	1.5V				
V <sub>OH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	3.0V	3.0V				
$t_r = t_r$	<2.0ns	<2.0ns	<2.5ns	<2.5ns				

Figure 4: Waveform - Propagation Delay (f=1MHz; 50% duty cycle)



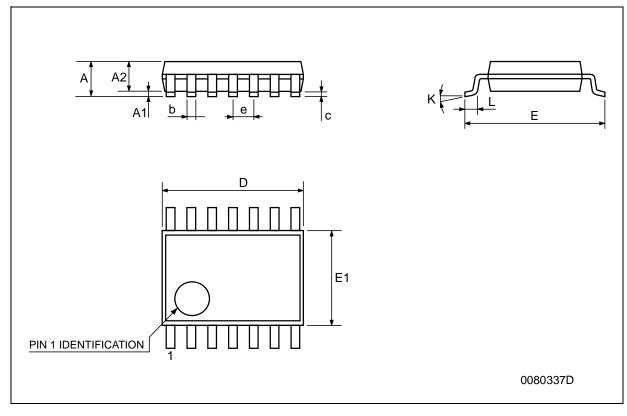
#### **SO-14 MECHANICAL DATA**

DIM		mm.			inch	
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А	1.35		1.75	0.053		0.069
A1	0.1		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	8.55		8.75	0.337		0.344
E	3.8		4.0	0.150		0.157
е		1.27			0.050	
Н	5.8		6.2	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.4		1.27	0.016		0.050
k	0°		8°	0°		8°
ddd			0.100			0.004



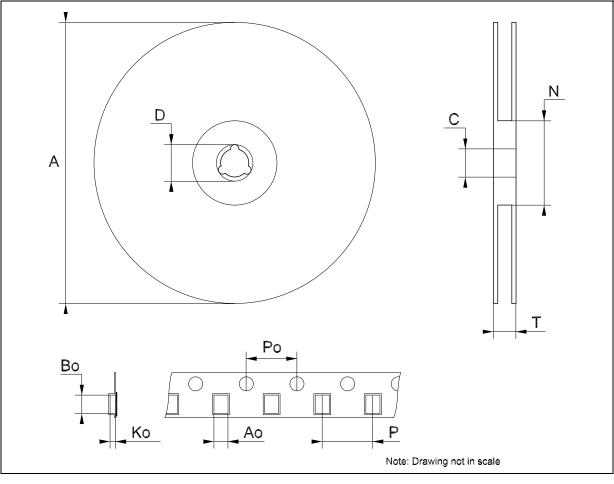
# **TSSOP14 MECHANICAL DATA**

DIM		mm.		inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65 BSC			0.0256 BSC	
К	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



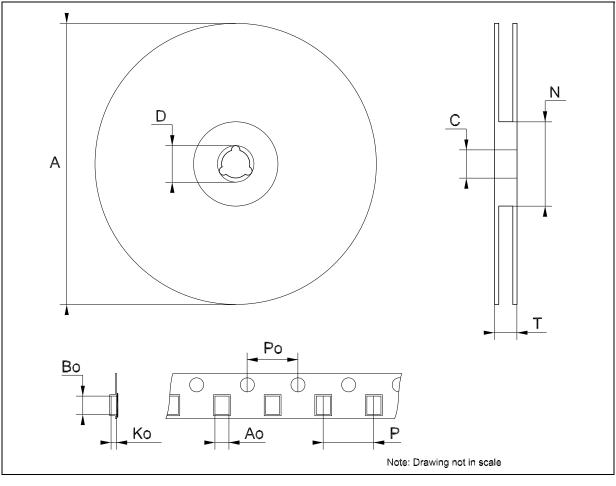
## Tape & Reel SO-14 MECHANICAL DATA

mm.			inch		
MIN.	TYP	MAX.	MIN.	TYP.	MAX.
		330			12.992
12.8		13.2	0.504		0.519
20.2			0.795		
60			2.362		
		22.4			0.882
6.4		6.6	0.252		0.260
9		9.2	0.354		0.362
2.1		2.3	0.082		0.090
3.9		4.1	0.153		0.161
7.9		8.1	0.311		0.319
	12.8 20.2 60 6.4 9 2.1 3.9	MIN. TYP  12.8  20.2  60  6.4  9  2.1  3.9	MIN.         TYP         MAX.           330         12.8         13.2           20.2         60         22.4           6.4         6.6         9           9         9.2           2.1         2.3           3.9         4.1	MIN.         TYP         MAX.         MIN.           330         12.8         13.2         0.504           20.2         0.795         0.795           60         2.362           22.4         6.6         0.252           9         9.2         0.354           2.1         2.3         0.082           3.9         4.1         0.153	MIN.         TYP         MAX.         MIN.         TYP.           12.8         13.2         0.504         0.795



## Tape & Reel TSSOP14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			22.4			0.882
Ao	6.7		6.9	0.264		0.272
Во	5.3		5.5	0.209		0.217
Ko	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



#### **Table 11: Revision History**

Date	Revision	Description of Changes
26-Jul-2004	4	Ordering Codes Revision - pag. 1.

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